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# 74LVC1T45; 74LVCH1T45

# Dual supply translating transceiver; 3-state Rev. 6 — 6 August 2012

**Product data sheet** 

#### **General description** 1.

The 74LVC1T45; 74LVCH1T45 are single bit, dual supply transceivers with 3-state outputs that enable bidirectional level translation. They feature two 1-bit input-output ports (A and B), a direction control input (DIR) and dual supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ). Both V<sub>CC(A)</sub> and V<sub>CC(B)</sub> can be supplied at any voltage between 1.2 V and 5.5 V making the device suitable for translating between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins A and DIR are referenced to  $V_{CC(A)}$  and pin B is referenced to V<sub>CC(B)</sub>. A HIGH on DIR allows transmission from A to B and a LOW on DIR allows transmission from B to A.

The devices are fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either  $V_{\text{CC(A)}}$  or  $V_{\text{CC(B)}}$  are at GND level, both A port and B port are in the high-impedance OFF-state.

Active bus hold circuitry in the 74LVCH1T45 holds unused or floating data inputs at a valid logic level.

#### Features and benefits 2.

- Wide supply voltage range:
  - ◆ V<sub>CC(A)</sub>: 1.2 V to 5.5 V
  - ◆ V<sub>CC(B)</sub>: 1.2 V to 5.5 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - ◆ JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 4000 V
  - CDM JESD22-C101E exceeds 1000 V
- Maximum data rates:
  - 420 Mbps (3.3 V to 5.0 V translation)
  - 210 Mbps (translate to 3.3 V))
  - 140 Mbps (translate to 2.5 V)
  - 75 Mbps (translate to 1.8 V)
  - 60 Mbps (translate to 1.5 V)
- Suspend mode



- Latch-up performance exceeds 100 mA per JESD 78 Class II
- $\pm$ 24 mA output drive (V<sub>CC</sub> = 3.0 V)
- Inputs accept voltages up to 5.5 V
- Low power consumption: 16 μA maximum I<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Ordering information

Table 1. Ordering information

| Type number  | Package           |       |   |         |  |  |  |  |
|--------------|-------------------|-------|---|---------|--|--|--|--|
|              | Temperature range | Name  | Description   | Version |  |  |  |  |
| 74LVC1T45GW  | –40 °C to +125 °C | SC-88 | plastic surface-mounted package; 6 leads                | SOT363  |  |  |  |  |
| 74LVCH1T45GW |                   |       |   |         |  |  |  |  |
| 74LVC1T45GM  | –40 °C to +125 °C |       |   | SOT886  |  |  |  |  |
| 74LVCH1T45GM |                   |       | 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm       |         |  |  |  |  |
| 74LVC1T45GF  | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; | SOT891  |  |  |  |  |
| 74LVCH1T45GF |                   |       | 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm          |         |  |  |  |  |
| 74LVC1T45GN  | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads;         | SOT1115 |  |  |  |  |
| 74LVCH1T45GN |                   |       | 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm       |         |  |  |  |  |
| 74LVC1T45GS  | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads;         | SOT1202 |  |  |  |  |
| 74LVCH1T45GS |                   |       | 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm       |         |  |  |  |  |

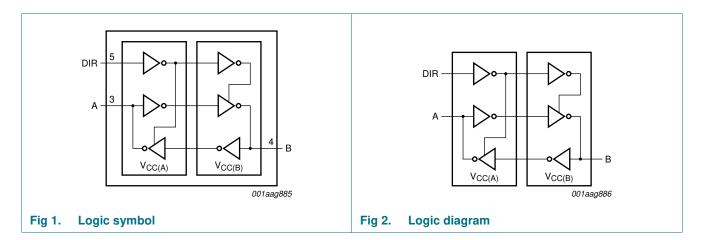
## 4. Marking

Table 2. Marking

| Type number  | Marking code <sup>[1]</sup> |
|--------------|-----------------------------|
| 74LVC1T45GW  | V5                          |
| 74LVCH1T45GW | X5                          |
| 74LVC1T45GM  | V5                          |
| 74LVCH1T45GM | X5                          |
| 74LVC1T45GF  | V5                          |
| 74LVCH1T45GF | X5                          |
| 74LVC1T45GN  | V5                          |
| 74LVCH1T45GN | X5                          |
| 74LVC1T45GS  | V5                          |
| 74LVCH1T45GS | X5                          |

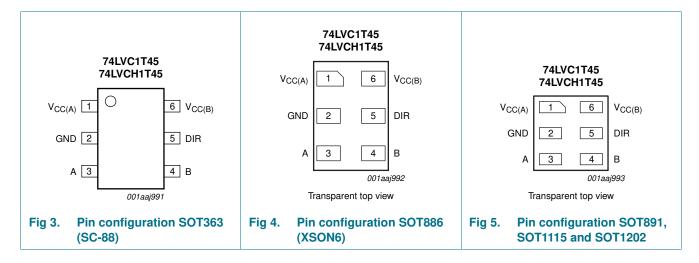
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



## 6. Pinning information

#### 6.1 Pinning



#### 6.2 Pin description

Table 3. Pin description

| Symbol      | Pin | Description                   |
|-------------|-----|-------------------------------|
| $V_{CC(A)}$ | 1   | supply voltage port A and DIR |
| GND         | 2   | ground (0 V)                  |
| Α           | 3   | data input or output          |
| В           | 4   | data input or output          |
| DIR         | 5   | direction control             |
| $V_{CC(B)}$ | 6   | supply voltage port B         |

## 7. Functional description

Table 4. Function table[1]

| Supply voltage                          | Input | Input/output <sup>[2]</sup> |       |  |  |
|---|-------|-----------------------------|-------|--|--|
| V <sub>CC(A)</sub> , V <sub>CC(B)</sub> | DIR   | A                           | В     |  |  |
| 1.2 V to 5.5 V                          | L     | A = B                       | input |  |  |
| 1.2 V to 5.5 V                          | Н     | input                       | B = A |  |  |
| GND[3]                                  | X     | Z                           | Z     |  |  |

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol             | Parameter               | Conditions   | Min             | Max             | Unit |
|--------------------|-------------------------|--|-----------------|-----------------|------|
| $V_{CC(A)}$        | supply voltage A        |  | -0.5            | +6.5            | V    |
| V <sub>CC(B)</sub> | supply voltage B        |  | -0.5            | +6.5            | V    |
| I <sub>IK</sub>    | input clamping current  | $V_I < 0 V$  | <b>–50</b>      | -               | mA   |
| VI                 | input voltage           |  | <u>[1]</u> –0.5 | +6.5            | V    |
| I <sub>OK</sub>    | output clamping current | V <sub>O</sub> < 0 V   | <b>–50</b>      | -               | mA   |
| V <sub>O</sub>     | output voltage          | Active mode  | [1][2][3] -0.5  | $V_{CCO} + 0.5$ | V    |
|                    |                         | Suspend or 3-state mode  | <u>[1]</u> –0.5 | +6.5            | V    |
| Io                 | output current          | $V_O = 0 V \text{ to } V_{CCO}$                                      | [2] -           | ±50             | mA   |
| I <sub>CC</sub>    | supply current          | $I_{CC(A)}$ or $I_{CC(B)}$   | -               | 100             | mA   |
| I <sub>GND</sub>   | ground current          |  | -100            | -               | mA   |
| T <sub>stg</sub>   | storage temperature     |  | -65             | +150            | °C   |
| P <sub>tot</sub>   | total power dissipation | $T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ | <u>[4]</u> _    | 250             | mW   |

<sup>[1]</sup> The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol      | Parameter        | Conditions | Min | Max | Unit |
|-------------|------------------|------------|-----|-----|------|
| $V_{CC(A)}$ | supply voltage A |            | 1.2 | 5.5 | V    |
| $V_{CC(B)}$ | supply voltage B |            | 1.2 | 5.5 | V    |
| VI          | input voltage    |            | 0   | 5.5 | V    |

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<sup>[2]</sup> The input circuit of the data I/O is always active.

<sup>[3]</sup> When either  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into suspend mode.

<sup>[2]</sup>  $V_{\text{CCO}}$  is the supply voltage associated with the output port.

<sup>[3]</sup>  $V_{CCO} + 0.5 \text{ V}$  should not exceed 6.5 V.

<sup>[4]</sup> For SC-88 package: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

Table 6. Recommended operating conditions ...continued

| Symbol              | Parameter                           | Conditions                                   | Min          | Max       | Unit |
|---------------------|-------------------------------------|--|--------------|-----------|------|
| $V_{O}$             | output voltage                      | Active mode                                  | <u>[1]</u> 0 | $V_{CCO}$ | V    |
|                     |                                     | Suspend or 3-state mode                      | 0            | 5.5       | V    |
| T <sub>amb</sub>    | ambient temperature                 |  | -40          | +125      | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | V <sub>CCI</sub> = 1.2 V                     | [2] -        | 20        | ns/V |
|                     |                                     | $V_{CCI} = 1.4 \text{ V to } 1.95 \text{ V}$ | -            | 20        | ns/V |
|                     |                                     | $V_{CCI} = 2.3 \text{ V to } 2.7 \text{ V}$  | -            | 20        | ns/V |
|                     |                                     | $V_{CCI} = 3 V \text{ to } 3.6 V$            | -            | 10        | ns/V |
|                     |                                     | $V_{CCI} = 4.5 \text{ V to } 5.5 \text{ V}$  | -            | 5         | ns/V |

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with the output port.

#### 10. Static characteristics

Table 7. Typical static characteristics at T<sub>amb</sub> = 25 °C

| Symbol            | Parameter                       | Conditions  |        | Min | Тур        | Max | Unit |
|-------------------|---------------------------------|---|--------|-----|------------|-----|------|
| $V_{OH}$          | HIGH-level output voltage       | $V_I = V_{IH}$ or $V_{IL}$  |        |     |            |     |      |
|                   |                                 | $I_O = -3 \text{ mA}; V_{CCO} = 1.2 \text{ V}$  | [1]    | -   | 1.09       | -   | V    |
| $V_{OL}$          | LOW-level output voltage        | $V_I = V_{IH}$ or $V_{IL}$  |        |     |            |     |      |
|                   |                                 | $I_O = 3 \text{ mA}; V_{CCO} = 1.2 \text{ V}$   | [1]    | -   | 0.07       | -   | V    |
| I <sub>I</sub>    | input leakage current           | DIR input; $V_1 = 0 \text{ V to } 5.5 \text{ V}$ ; $V_{CCI} = 1.2 \text{ V to } 5.5 \text{ V}$    | [2]    | -   | -          | ±1  | μΑ   |
| I <sub>BHL</sub>  | bus hold LOW current            | A or B port; $V_I = 0.42 \text{ V}$ ; $V_{CCI} = 1.2 \text{ V}$                                   | [2]    | -   | 19         | -   | μΑ   |
| I <sub>BHH</sub>  | bus hold HIGH current           | A or B port; $V_I = 0.78 \text{ V}$ ; $V_{CCI} = 1.2 \text{ V}$                                   | [2]    | -   | <b>-19</b> | -   | μΑ   |
| I <sub>BHLO</sub> | bus hold LOW overdrive current  | A or B port; $V_{CCI} = 1.2 \text{ V}$  | [2][3] | -   | 19         | -   | μΑ   |
| Івнно             | bus hold HIGH overdrive current | A or B port; $V_{CCI} = 1.2 \text{ V}$  | [2][3] | -   | –19        | -   | μΑ   |
| l <sub>OZ</sub>   | OFF-state output current        | A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CCO} = 1.2 \text{ V to } 5.5 \text{ V}$        | [1]    | -   | -          | ±1  | μΑ   |
| I <sub>OFF</sub>  | power-off leakage current       | A port; $V_1$ or $V_0 = 0$ V to 5.5 V;<br>$V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.2$ V to 5.5 V         |        | -   | -          | ±1  | μΑ   |
|                   |                                 | B port; $V_1$ or $V_0 = 0$ V to 5.5 V;<br>$V_{CC(B)} = 0$ V; $V_{CC(A)} = 1.2$ V to 5.5 V         |        | -   | -          | ±1  | μΑ   |
| C <sub>I</sub>    | input capacitance               | DIR input; $V_1 = 0 \text{ V or } 3.3 \text{ V}$ ; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$        |        | -   | 2.2        | -   | pF   |
| C <sub>I/O</sub>  | input/output capacitance        | A and B port; suspend mode; $V_O = 3.3 \text{ V}$ or 0 V; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$ |        | -   | 6.0        | -   | pF   |

<sup>[1]</sup>  $V_{\text{CCO}}$  is the supply voltage associated with the output port.

<sup>[2]</sup>  $V_{CCI}$  is the supply voltage associated with the input port.

<sup>[2]</sup>  $V_{CCI}$  is the supply voltage associated with the data input port.

<sup>[3]</sup> To guarantee the node switches, an external driver must source/sink at least  $I_{BHLO}/I_{BHHO}$  when the input is in the range  $V_{IL}$  to  $V_{IH}$ .

Table 8. Static characteristics

| Symbol               | Parameter      | Conditions   | –40 °C                     | to +85 °C              | -40 °C to              | -40 °C to +125 °C      |   |
|----------------------|----------------|--|----------------------------|------------------------|------------------------|------------------------|---|
|                      |                |  | Min                        | Max                    | Min                    | Max                    |   |
| $V_{IH}$             | HIGH-level     | data input   | <u>[1]</u>                 |                        |                        |                        |   |
|                      | input voltage  | V <sub>CCI</sub> = 1.2 V   | 0.8V <sub>CCI</sub>        | -                      | 0.8V <sub>CCI</sub>    | -                      | V |
| V <sub>IH</sub> H in |                | V <sub>CCI</sub> = 1.4 V to 1.95 V                                   | 0.65V <sub>CCI</sub>       | -                      | 0.65V <sub>CCI</sub>   | -                      | V |
|                      |                | V <sub>CCI</sub> = 2.3 V to 2.7 V                                    | 1.7                        | -                      | 1.7                    | -                      | V |
|                      |                | V <sub>CCI</sub> = 3.0 V to 3.6 V                                    | 2.0                        | -                      | 2.0                    | -                      | V |
|                      |                | V <sub>CCI</sub> = 4.5 V to 5.5 V                                    | 0.7V <sub>CCI</sub>        | -                      | 0.7V <sub>CCI</sub>    | -                      | V |
|                      |                | DIR input  |                            |                        |                        |                        |   |
|                      |                | V <sub>CCI</sub> = 1.2 V   | 0.8V <sub>CC(A)</sub>      | -                      | 0.8V <sub>CC(A)</sub>  | -                      | V |
|                      |                | V <sub>CCI</sub> = 1.4 V to 1.95 V                                   | 0.65V <sub>CC(A)</sub>     | -                      | 0.65V <sub>CC(A)</sub> | -                      | V |
|                      |                | V <sub>CCI</sub> = 2.3 V to 2.7 V                                    | 1.7                        | -                      | 1.7                    | -                      | V |
|                      |                | V <sub>CCI</sub> = 3.0 V to 3.6 V                                    | 2.0                        | -                      | 2.0                    | -                      | V |
|                      |                | V <sub>CCI</sub> = 4.5 V to 5.5 V                                    | 0.7V <sub>CC(A)</sub>      | -                      | 0.7V <sub>CC(A)</sub>  | -                      | V |
| $V_{IL}$             | LOW-level      | data input   | <u>[1]</u>                 |                        |                        |                        |   |
|                      | input voltage  | V <sub>CCI</sub> = 1.2 V   | -                          | 0.2V <sub>CCI</sub>    | -                      | 0.2V <sub>CCI</sub>    | V |
|                      |                | V <sub>CCI</sub> = 1.4 V to 1.95 V                                   | -                          | $0.35V_{CCI}$          | -                      | 0.35V <sub>CCI</sub>   | V |
|                      |                | V <sub>CCI</sub> = 2.3 V to 2.7 V                                    | -                          | 0.7                    | -                      | 0.7                    | V |
|                      |                | V <sub>CCI</sub> = 3.0 V to 3.6 V                                    | -                          | 0.8                    | -                      | 8.0                    | V |
|                      |                | V <sub>CCI</sub> = 4.5 V to 5.5 V                                    | -                          | 0.3V <sub>CCI</sub>    | -                      | 0.3V <sub>CCI</sub>    | V |
|                      |                | DIR input  |                            |                        |                        |                        |   |
|                      |                | V <sub>CCI</sub> = 1.2 V   | -                          | 0.2V <sub>CC(A)</sub>  | -                      | 0.2V <sub>CC(A)</sub>  | V |
|                      |                | V <sub>CCI</sub> = 1.4 V to 1.95 V                                   | -                          | 0.35V <sub>CC(A)</sub> | -                      | 0.35V <sub>CC(A)</sub> | V |
|                      |                | V <sub>CCI</sub> = 2.3 V to 2.7 V                                    | -                          | 0.7                    | -                      | 0.7                    | V |
|                      |                | V <sub>CCI</sub> = 3.0 V to 3.6 V                                    | -                          | 0.8                    | -                      | 0.8                    | V |
|                      |                | V <sub>CCI</sub> = 4.5 V to 5.5 V                                    | -                          | 0.3V <sub>CC(A)</sub>  | -                      | $0.3V_{CC(A)}$         | V |
| $V_{OH}$             | HIGH-level     | $V_I = V_{IH}$   |                            |                        |                        |                        |   |
|                      | output voltage | $I_{O} = -100 \mu A;$<br>$V_{CCO} = 1.2 \text{ V to } 4.5 \text{ V}$ | [2] V <sub>CCO</sub> – 0.1 | -                      | V <sub>CCO</sub> - 0.1 | -                      | V |
|                      |                | $I_O = -6 \text{ mA}; V_{CCO} = 1.4 \text{ V}$                       | 1.0                        | -                      | 1.0                    | -                      | V |
|                      |                | $I_{O} = -8 \text{ mA}; V_{CCO} = 1.65 \text{ V}$                    | 1.2                        | -                      | 1.2                    | -                      | V |
|                      |                | $I_{O} = -12 \text{ mA}; V_{CCO} = 2.3 \text{ V}$                    | 1.9                        | -                      | 1.9                    | -                      | V |
|                      |                | $I_{O} = -24 \text{ mA}; V_{CCO} = 3.0 \text{ V}$                    | 2.4                        | -                      | 2.4                    | -                      | V |
|                      |                | $I_{O} = -32 \text{ mA}; V_{CCO} = 4.5 \text{ V}$                    | 3.8                        | -                      | 3.8                    | -                      | V |

 Table 8.
 Static characteristics ...continued

| Symbol           | Parameter                | Conditions   |        | -40 °C t   | o +85 °C  | -40 °C to | +125 °C | Unit |
|------------------|--------------------------|--|--------|------------|-----------|-----------|---------|------|
|                  |                          |  |        | Min        | Max       | Min       | Max     |      |
| V <sub>OL</sub>  | LOW-level                | $V_I = V_{IL}$   | [2]    |            |           |           |         |      |
|                  | output voltage           | $I_O = 100 \mu A;$<br>$V_{CCO} = 1.2 \text{ V to } 4.5 \text{ V}$                              |        | -          | 0.1       | -         | 0.1     | V    |
|                  |                          | $I_O = 6 \text{ mA}; V_{CCO} = 1.4 \text{ V}$  |        | -          | 0.3       | -         | 0.3     | V    |
|                  |                          | $I_O = 8 \text{ mA}; V_{CCO} = 1.65 \text{ V}$   |        | -          | 0.45      | -         | 0.45    | V    |
|                  |                          | $I_O = 12 \text{ mA}; V_{CCO} = 2.3 \text{ V}$   |        | -          | 0.3       | -         | 0.3     | V    |
|                  |                          | $I_O = 24 \text{ mA}; V_{CCO} = 3.0 \text{ V}$   |        | -          | 0.55      | -         | 0.55    | V    |
|                  |                          | $I_O = 32 \text{ mA}; V_{CCO} = 4.5 \text{ V}$   |        | -          | 0.55      | -         | 0.55    | V    |
| lı               | input leakage<br>current | DIR input; $V_I = 0 \text{ V to } 5.5 \text{ V}$ ; $V_{CCI} = 1.2 \text{ V to } 5.5 \text{ V}$ |        | -          | <u>+2</u> | -         | ±10     | μА   |
| I <sub>BHL</sub> | bus hold LOW             | A or B port  | [1]    |            |           |           |         |      |
|                  | current                  | V <sub>I</sub> = 0.49 V; V <sub>CCI</sub> = 1.4 V  |        | 15         | -         | 10        | -       | μА   |
|                  |                          | V <sub>I</sub> = 0.58 V; V <sub>CCI</sub> = 1.65 V   |        | 25         | -         | 20        | -       | μА   |
|                  |                          | V <sub>I</sub> = 0.70 V; V <sub>CCI</sub> = 2.3 V  |        | 45         | -         | 45        | -       | μА   |
|                  |                          | V <sub>I</sub> = 0.80 V; V <sub>CCI</sub> = 3.0 V  |        | 100        | -         | 80        | -       | μА   |
|                  |                          | $V_I = 1.35 \text{ V}; V_{CCI} = 4.5 \text{ V}$  |        | 100        | -         | 100       | -       | μΑ   |
| I <sub>BHH</sub> | bus hold HIGH<br>current | A or B port  | [1]    |            |           |           |         |      |
|                  |                          | $V_I = 0.91 \text{ V}; V_{CCI} = 1.4 \text{ V}$  |        | <b>−15</b> | -         | -10       | -       | μА   |
|                  |                          | $V_I = 1.07 \text{ V}; V_{CCI} = 1.65 \text{ V}$   |        | -25        | -         | -20       | -       | μΑ   |
|                  |                          | $V_I = 1.60 \text{ V}; V_{CCI} = 2.3 \text{ V}$  |        | <b>-45</b> | -         | -45       | -       | μΑ   |
|                  |                          | $V_{I} = 2.00 \text{ V}; V_{CCI} = 3.0 \text{ V}$  |        | -100       | -         | -80       | -       | μΑ   |
|                  |                          | $V_I = 3.15 \text{ V}; V_{CCI} = 4.5 \text{ V}$  |        | -100       | -         | -100      | -       | μΑ   |
| $I_{BHLO}$       | bus hold LOW             | A or B port  | [1][3] |            |           |           |         |      |
|                  | overdrive<br>current     | $V_{CCI} = 1.6 V$  |        | 125        | -         | 125       | -       | μΑ   |
|                  | Current                  | $V_{CCI} = 1.95 V$   |        | 200        | -         | 200       | -       | μΑ   |
|                  |                          | $V_{CCI} = 2.7 V$  |        | 300        | -         | 300       | -       | μΑ   |
|                  |                          | $V_{CCI} = 3.6 V$  |        | 500        | -         | 500       | -       | μА   |
|                  |                          | $V_{CCI} = 5.5 V$  |        | 900        | -         | 900       | -       | μΑ   |
| $I_{BHHO}$       | bus hold HIGH            | A or B port  | [1][3] |            |           |           |         |      |
|                  | overdrive<br>current     | $V_{CCI} = 1.6 V$  |        | -125       | -         | -125      | -       | μΑ   |
|                  | Janon                    | $V_{CCI} = 1.95 V$   |        | -200       | -         | -200      | -       | μΑ   |
|                  |                          | $V_{CCI} = 2.7 V$  |        | -300       | -         | -300      | -       | μΑ   |
|                  |                          | $V_{CCI} = 3.6 V$  |        | -500       | -         | -500      | -       | μΑ   |
|                  |                          | V <sub>CCI</sub> = 5.5 V   |        | -900       | -         | -900      | -       | μΑ   |
| l <sub>OZ</sub>  | OFF-state output current | A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CCO} = 1.2 \text{ V to } 5.5 \text{ V}$     | [2]    | -          | ±2        | -         | ±10     | μΑ   |

 Table 8.
 Static characteristics ...continued

| Symbol           | Parameter                       | Conditions  |     | -40 °C 1 | to +85 °C | -40 °C to | +125 °C | Unit |
|------------------|---------------------------------|---|-----|----------|-----------|-----------|---------|------|
|                  |                                 |   |     | Min      | Max       | Min       | Max     |      |
| I <sub>OFF</sub> | power-off<br>leakage<br>current | A port; $V_I$ or $V_O = 0$ V to 5.5 V;<br>$V_{CC(A)} = 0$ V;<br>$V_{CC(B)} = 1.2$ V to 5.5 V      |     | -        | ±2        | -         | ±10     | μА   |
|                  |                                 | B port; $V_I$ or $V_O = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 1.2$ V to 5.5 V            |     | -        | ±2        | -         | ±10     | μА   |
| I <sub>CC</sub>  | supply current                  | A port; $V_I = 0 V \text{ or } V_{CCI}$ ; $I_O = 0 A$   | [1] |          |           |           |         |      |
|                  |                                 | $V_{CC(A)}$ , $V_{CC(B)} = 1.2 \text{ V to } 5.5 \text{ V}$                                       |     | -        | 8         | -         | 8       | μΑ   |
|                  |                                 | $V_{CC(A)}$ , $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$                                      |     | -        | 3         | -         | 3       | μΑ   |
|                  |                                 | $V_{CC(A)} = 5.5 \text{ V}; V_{CC(B)} = 0 \text{ V}$  |     | -        | 2         | -         | 2       | μΑ   |
|                  |                                 | $V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 5.5 \text{ V}$  |     | -2       | -         | -2        | -       | μΑ   |
|                  |                                 | B port; $V_I = 0 \text{ V or } V_{CCI}$ ; $I_O = 0 \text{ A}$                                     |     |          |           |           |         |      |
|                  |                                 | $V_{CC(A)}$ , $V_{CC(B)} = 1.2 \text{ V to } 5.5 \text{ V}$                                       |     | -        | 8         | -         | 8       | μΑ   |
|                  |                                 | $V_{CC(A)}$ , $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$                                      |     | -        | 3         | -         | 3       | μΑ   |
|                  |                                 | $V_{CC(B)} = 5.5 \text{ V}; V_{CC(A)} = 0 \text{ V}$  |     | -        | 2         | -         | 2       | μΑ   |
|                  |                                 | $V_{CC(B)} = 0 \text{ V}; V_{CC(A)} = 5.5 \text{ V}$  |     | -2       | -         | -2        | -       | μΑ   |
|                  |                                 | A plus B port $(I_{CC(A)} + I_{CC(B)})$ ;<br>$I_O = 0$ A; $V_I = 0$ V or $V_{CCI}$                |     |          |           |           |         |      |
|                  |                                 | $V_{CC(A)}$ , $V_{CC(B)} = 1.2 \text{ V to } 5.5 \text{ V}$                                       |     | -        | 16        | -         | 16      | μΑ   |
|                  |                                 | $V_{CC(A)}, V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$   |     | -        | 4         | -         | 4       | μΑ   |
| $\Delta I_{CC}$  | additional                      | $V_{CC(A)}$ , $V_{CC(B)} = 3.0 \text{ V to } 5.5 \text{ V}$                                       |     |          |           |           |         |      |
|                  | supply current                  | A port; A port at $V_{CC(A)} - 0.6 \text{ V}$ ; DIR at $V_{CC(A)}$ ; B port = open                | [4] | -        | 50        | -         | 75      | μА   |
|                  |                                 | DIR input; DIR at $V_{CC(A)} - 0.6 \text{ V}$ ;<br>A port at $V_{CC(A)}$ or GND;<br>B port = open |     | -        | 50        | -         | 75      | μА   |
|                  |                                 | B port; B port at $V_{CC(B)} - 0.6 \text{ V}$ ;<br>DIR at GND; A port = open                      | [4] | -        | 50        | -         | 75      | μА   |

<sup>[1]</sup>  $V_{CCI}$  is the supply voltage associated with the data input port.

<sup>[2]</sup>  $V_{CCO}$  is the supply voltage associated with the output port.

<sup>[3]</sup> To guarantee the node switches, an external driver must source/sink at least  $I_{BHLO}/I_{BHHO}$  when the input is in the range  $V_{IL}$  to  $V_{IH}$ .

<sup>[4]</sup> For non bus hold parts only (74LVC1T45).

# 11. Dynamic characteristics

Table 9. Typical dynamic characteristics at  $V_{CC(A)} = 1.2 \text{ V}$  and  $T_{amb} = 25 \text{ °C}$ Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 8</u>; for waveforms see <u>Figure 6</u> and <u>Figure 7</u>

| Symbol   | Parameter                     | Conditions | V <sub>CC(B)</sub> |       |       |       |       |       | Unit |
|--|-------------------------------|------------|--------------------|-------|-------|-------|-------|-------|------|
|  |                               |            | 1.2 V              | 1.5 V | 1.8 V | 2.5 V | 3.3 V | 5.0 V |      |
| t <sub>PLH</sub>                               | LOW to HIGH propagation delay | A to B     | 10.6               | 8.1   | 7.0   | 5.8   | 5.3   | 5.1   | ns   |
|  |                               | B to A     | 10.6               | 9.5   | 9.0   | 8.5   | 8.3   | 8.2   | ns   |
| t <sub>PHL</sub> HIGH to LOW propagation delay | A to B                        | 10.1       | 7.1                | 6.0   | 5.3   | 5.2   | 5.4   | ns    |      |
|  | propagation delay             | B to A     | 10.1               | 8.6   | 8.1   | 7.8   | 7.6   | 7.6   | ns   |
| t <sub>PHZ</sub>                               | HIGH to OFF-state             | DIR to A   | 9.4                | 9.4   | 9.4   | 9.4   | 9.4   | 9.4   | ns   |
|  | propagation delay             | DIR to B   | 12.0               | 9.4   | 9.0   | 7.8   | 8.4   | 7.9   | ns   |
| t <sub>PLZ</sub>                               | LOW to OFF-state              | DIR to A   | 7.1                | 7.1   | 7.1   | 7.1   | 7.1   | 7.1   | ns   |
|  | propagation delay             | DIR to B   | 9.5                | 7.8   | 7.7   | 6.9   | 7.6   | 7.0   | ns   |
| t <sub>PZH</sub>                               | OFF-state to HIGH             | DIR to A   | 20.1               | 17.3  | 16.7  | 15.4  | 15.9  | 15.2  | ns   |
|  | propagation delay             | DIR to B   | 17.7               | 15.2  | 14.1  | 12.9  | 12.4  | 12.2  | ns   |
| t <sub>PZL</sub>                               | OFF-state to LOW              | DIR to A   | 22.1               | 18.0  | 17.1  | 15.6  | 16.0  | 15.5  | ns   |
|  | propagation delay             | DIR to B   | 19.5               | 16.5  | 15.4  | 14.7  | 14.6  | 14.8  | ns   |

<sup>[1]</sup> t<sub>PZH</sub> and t<sub>PZL</sub> are calculated values using the formula shown in Section 14.4 "Enable times"

Table 10. Typical dynamic characteristics at  $V_{CC(B)} = 1.2 \text{ V}$  and  $T_{amb} = 25 \text{ °C}$ Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 8</u>; for waveforms see <u>Figure 6</u> and <u>Figure 7</u>

| Symbol           | Parameter         | Conditions |       |       | Vc    | C(A)  |       |       | Unit |
|------------------|-------------------|------------|-------|-------|-------|-------|-------|-------|------|
|                  |                   |            | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 3.3 V | 5.0 V |      |
| t <sub>PLH</sub> | LOW to HIGH       | A to B     | 10.6  | 9.5   | 9.0   | 8.5   | 8.3   | 8.2   | ns   |
|                  | propagation delay | B to A     | 10.6  | 8.1   | 7.0   | 5.8   | 5.3   | 5.1   | ns   |
| t <sub>PHL</sub> | HIGH to LOW       | A to B     | 10.1  | 8.6   | 8.1   | 7.8   | 7.6   | 7.6   | ns   |
|                  | propagation delay | B to A     | 10.1  | 7.1   | 6.0   | 5.3   | 5.2   | 5.4   | ns   |
| t <sub>PHZ</sub> | HIGH to OFF-state | DIR to A   | 9.4   | 6.5   | 5.7   | 4.1   | 4.1   | 3.0   | ns   |
|                  | propagation delay | DIR to B   | 12.0  | 6.1   | 5.4   | 4.6   | 4.3   | 4.0   | ns   |
| t <sub>PLZ</sub> | LOW to OFF-state  | DIR to A   | 7.1   | 4.9   | 4.5   | 3.2   | 3.4   | 2.5   | ns   |
|                  | propagation delay | DIR to B   | 9.5   | 7.3   | 6.6   | 5.9   | 5.7   | 5.6   | ns   |
| t <sub>PZH</sub> | OFF-state to HIGH | DIR to A   | 20.1  | 15.4  | 13.6  | 11.7  | 11.0  | 10.7  | ns   |
|                  | propagation delay | DIR to B   | 17.7  | 14.4  | 13.5  | 11.7  | 11.7  | 10.7  | ns   |
| t <sub>PZL</sub> | OFF-state to LOW  | DIR to A   | 22.1  | 13.2  | 11.4  | 9.9   | 9.5   | 9.4   | ns   |
|                  | propagation delay | DIR to B   | 19.5  | 15.1  | 13.8  | 11.9  | 11.7  | 10.6  | ns   |

<sup>[1]</sup>  $t_{PZH}$  and  $t_{PZL}$  are calculated values using the formula shown in Section 14.4 "Enable times"

Table 11. Typical power dissipation capacitance at  $V_{CC(A)} = V_{CC(B)}$  and  $T_{amb} = 25 \, ^{\circ}C \, \frac{[1][2]}{C}$ 

Voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                     | Conditions  |       | V <sub>CC(A)</sub> ar | nd V <sub>CC(B)</sub> |       | Unit |
|----------|-------------------------------|---|-------|-----------------------|-----------------------|-------|------|
|          |                               |   | 1.8 V | 2.5 V                 | 3.3 V                 | 5.5 V |      |
| $C_{PD}$ | power dissipation capacitance | A port: (direction A to B);<br>B port: (direction B to A) | 2     | 3                     | 3                     | 4     | pF   |
|          |                               | A port: (direction B to A);<br>B port: (direction A to B) | 15    | 16                    | 16                    | 18    | pF   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2]  $f_i = 10$  MHz;  $V_I = GND$  to  $V_{CC}$ ;  $t_r = t_f = 1$  ns;  $C_L = 0$  pF;  $R_L = \infty \Omega$ .

Table 12. Dynamic characteristics for temperature range -40 °C to +85 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7

| Symbol               | Parameter         | Conditions   |         |       |         |        | Vcc     | (B)     |         |         |         |       | Unit |
|----------------------|-------------------|--------------|---------|-------|---------|--------|---------|---------|---------|---------|---------|-------|------|
|                      |                   |              | 1.5 V ± | 0.1 V | 1.8 V ± | 0.15 V | 2.5 V ± | ± 0.2 V | 3.3 V ± | ± 0.3 V | 5.0 V ± | 0.5 V |      |
|                      |                   |              | Min     | Max   | Min     | Max    | Min     | Max     | Min     | Max     | Min     | Max   |      |
| V <sub>CC(A)</sub> = | 1.4 V to 1.6 V    | '            |         |       | •       | '      | '       | •       | •       |         |         |       |      |
| t <sub>PLH</sub>     | LOW to HIGH       | A to B       | 2.8     | 21.3  | 2.4     | 17.6   | 2.0     | 13.5    | 1.7     | 11.8    | 1.6     | 10.5  | ns   |
|                      | propagation delay | B to A       | 2.8     | 21.3  | 2.6     | 19.1   | 2.3     | 14.9    | 2.3     | 12.4    | 2.2     | 12.0  | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.6     | 19.3  | 2.2     | 15.3   | 1.8     | 11.8    | 1.7     | 10.9    | 1.7     | 10.8  | ns   |
|                      | propagation delay | B to A       | 2.6     | 19.3  | 2.4     | 17.3   | 2.3     | 13.2    | 2.2     | 11.3    | 2.3     | 11.0  | ns   |
| $t_{\text{PHZ}}$     | HIGH to OFF-state | DIR to A     | 3.0     | 18.7  | 3.0     | 18.7   | 3.0     | 18.7    | 3.0     | 18.7    | 3.0     | 18.7  | ns   |
|                      | propagation delay | DIR to B     | 3.5     | 24.8  | 3.5     | 23.6   | 3.0     | 11.0    | 3.3     | 11.3    | 2.8     | 10.3  | ns   |
| $t_{\text{PLZ}}$     | LOW to OFF-state  | DIR to A     | 2.4     | 11.4  | 2.4     | 11.4   | 2.4     | 11.4    | 2.4     | 11.4    | 2.4     | 11.4  | ns   |
|                      | propagation delay | DIR to B     | 2.8     | 18.3  | 3.0     | 17.2   | 2.5     | 9.4     | 3.0     | 10.1    | 2.5     | 9.4   | ns   |
| $t_{PZH}$            | OFF-state to HIGH | DIR to A [1] | -       | 39.6  | -       | 36.3   | -       | 24.3    | -       | 22.5    | -       | 21.4  | ns   |
|                      | propagation delay | DIR to B 🗓   | -       | 32.7  | -       | 29.0   | -       | 24.9    | -       | 23.2    | -       | 21.9  | ns   |
| t <sub>PZL</sub>     | OFF-state to LOW  | DIR to A [1] | -       | 44.1  | -       | 40.9   | -       | 24.2    | -       | 22.6    | -       | 21.3  | ns   |
|                      | propagation delay | DIR to B 🗓   | -       | 38.0  | -       | 34.0   | -       | 30.5    | -       | 29.6    | -       | 29.5  | ns   |
| V <sub>CC(A)</sub> = | 1.65 V to 1.95 V  |              |         |       |         |        |         |         |         |         |         |       |      |
| t <sub>PLH</sub>     | LOW to HIGH       | A to B       | 2.6     | 19.1  | 2.2     | 17.7   | 2.2     | 9.3     | 1.7     | 7.2     | 1.4     | 6.8   | ns   |
|                      | propagation delay | B to A       | 2.4     | 17.6  | 2.2     | 17.7   | 2.3     | 16.0    | 2.1     | 15.5    | 1.9     | 15.1  | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.4     | 17.3  | 2.0     | 14.3   | 1.6     | 8.5     | 1.8     | 7.1     | 1.7     | 7.0   | ns   |
|                      | propagation delay | B to A       | 2.2     | 15.3  | 2.0     | 14.3   | 2.1     | 12.9    | 2.0     | 12.6    | 1.8     | 12.2  | ns   |
| t <sub>PHZ</sub>     | HIGH to OFF-state | DIR to A     | 2.9     | 17.1  | 2.9     | 17.1   | 2.9     | 17.1    | 2.9     | 17.1    | 2.9     | 17.1  | ns   |
|                      | propagation delay | DIR to B     | 3.2     | 24.1  | 3.2     | 21.9   | 2.7     | 11.5    | 3.0     | 10.3    | 2.5     | 8.2   | ns   |
| $t_{PLZ}$            | LOW to OFF-state  | DIR to A     | 2.4     | 10.5  | 2.4     | 10.5   | 2.4     | 10.5    | 2.4     | 10.5    | 2.4     | 10.5  | ns   |
|                      | proposition dolar | DIR to B     | 2.5     | 17.6  | 2.6     | 16.0   | 2.2     | 9.2     | 2.7     | 8.4     | 2.4     | 6.4   | ns   |

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Dynamic characteristics for temperature range -40 °C to +85 °C ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7 Symbol Parameter Conditions V<sub>CC(B)</sub> Unit 1.5 V ± 0.1 V 1.8 V ± 0.15 V  $2.5 V \pm 0.2 V$  $5.0 V \pm 0.5 V$  $3.3 \text{ V} \pm 0.3 \text{ V}$ Min Min Max Max Max Min Min Max Min Max [1] OFF-state to HIGH DIR to A 35.2 \_ 33.7 25.2 23.9 \_ 21.8 t<sub>P7H</sub> ns propagation delay DIR to B [1] 29.6 28.2 19.8 17.7 17.3 ns OFF-state to LOW DIR to A [1] 39.4 36.2 22.9 24.4 20.4  $t_{PZL}$ \_ ns propagation delay [1] DIR to B 34.4 31.4 25.6 24.2 24.1 ns  $V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$ 2.3 17.9 2.3 16.0 6.2 LOW to HIGH A to B 1.5 8.5 1.3 1.1 4.8  $t_{PLH}$ ns propagation delay B to A 2.0 13.5 2.2 9.3 1.5 8.5 1.4 8.0 1.0 7.5 ns HIGH to LOW A to B 2.3 15.8 2.1 12.9 1.4 7.5 1.3 5.4 0.9 4.6  $t_{PHL}$ ns propagation delay B to A 1.9 8.5 7.5 1.3 7.0 0.9 1.8 11.8 1.4 6.2 ns HIGH to OFF-state DIR to A 2.1 8.1 2.1 8.1 2.1 8.1 2.1 8.1 2.1 8.1 ns  $t_{PHZ}$ propagation delay DIR to B 3.0 22.5 3.0 21.4 2.5 11.0 2.8 9.3 2.3 6.9 ns LOW to OFF-state 1.7 5.8 1.7 5.8 5.8 1.7 5.8 1.7 5.8 DIR to A 1.7  $t_{PLZ}$ ns propagation delay DIR to B 2.3 14.6 2.5 13.2 2.0 9.0 2.5 8.4 1.8 5.3 ns OFF-state to HIGH DIR to A [1] 28.1 22.5 17.5 16.4 -12.8 \_ \_  $t_{PZH}$ ns propagation delay DIR to B [1] 23.7 12.0 21.8 14.3 10.6 ns OFF-state to LOW DIR to A [1] 34.3 29.9 18.5 16.3 13.1  $t_{PZL}$ ns propagation delay [1] DIR to B 23.9 21.0 15.6 13.5 12.7 \_ \_ \_ \_ ns  $V_{CC(A)} = 3.0 \text{ V to } 3.6 \text{ V}$ LOW to HIGH A to B 2.3 17.1 2.1 15.5 1.4 8.0 0.8 5.6 0.7 4.4 ns  $t_{PLH}$ propagation delay B to A 11.8 1.7 7.2 1.3 6.2 0.7 5.6 0.6 5.4 1.7 ns 2.2 HIGH to LOW A to B 15.6 2.0 12.6 1.3 7.0 8.0 5.0 0.7  $t_{PHL}$ 4.0 ns propagation delay B to A 1.7 10.9 1.8 7.1 5.4 0.8 5.0 0.7 1.3 4.5 ns HIGH to OFF-state DIR to A 2.3 7.3 2.3 7.3 7.3 2.3 7.3 2.7 23 7.3  $t_{PHZ}$ ns propagation delay 2.9 2.7 DIR to B 2.9 18.0 2.3 2.2 16.5 10.1 8.6 6.3 ns LOW to OFF-state DIR to A 2.0 5.6 2.0 5.6 5.6 2.0 5.6 2.0 2.0 5.6 ns  $t_{PLZ}$ propagation delay DIR to B 2.3 13.6 2.4 12.5 1.9 7.8 2.3 7.1 1.7 4.9 ns [1] OFF-state to HIGH DIR to A 25.4 19.7 14.0 12.7 10.3 ns  $t_{PZH}$ propagation delay DIR to B [1] 22.7 13.6 21.1 11.2 10.0 ns DIR to A [1] 28.9 OFF-state to LOW 23.6 15.5 13.6 10.8 \_ --\_ ns  $t_{PZL}$ propagation delay [1] DIR to B 22.9 19.9 14.3 12.3 11.3 ns  $V_{CC(A)} = 4.5 \text{ V to } 5.5 \text{ V}$ LOW to HIGH A to B 2.2 16.6 1.9 15.1 1.0 7.5 0.7 5.4 0.5 3.9  $t_{PLH}$ ns propagation delay B to A 1.6 10.5 1.4 1.0 4.8 0.7 4.4 0.5 3.9 6.8 ns 2.3 15.3 1.8 12.2 0.7 4.5 0.5 HIGH to LOW A to B 1.0 6.2 3.5  $t_{PHL}$ ns propagation delay B to A 1.7 10.8 1.7 7.0 0.9 4.6 0.7 4.0 0.5 3.5 ns HIGH to OFF-state DIR to A 1.7 5.4 1.7 1.7 1.7 5.4 1.7 5.4 5.4 5.4 ns  $t_{PHZ}$ propagation delay

2.9

16.1

2.3

9.7

DIR to B

2.9

17.3

5.7

2.7

8.0

2.5

ns

Table 12. Dynamic characteristics for temperature range -40 °C to +85 °C ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7

| Symbol           | Parameter  | Conditions V <sub>CC(B)</sub> |         |         |         |        |         |         |         | Unit  |         |       |    |
|------------------|--|-------------------------------|---------|---------|---------|--------|---------|---------|---------|-------|---------|-------|----|
|                  |  |                               | 1.5 V ± | Ŀ 0.1 V | 1.8 V ± | 0.15 V | 2.5 V ± | Ŀ 0.2 V | 3.3 V ± | 0.3 V | 5.0 V ± | 0.5 V |    |
|                  |  |                               | Min     | Max     | Min     | Max    | Min     | Max     | Min     | Max   | Min     | Max   |    |
| $t_{PLZ}$        | LOW to OFF-state   | DIR to A                      | 1.4     | 3.7     | 1.4     | 3.7    | 1.3     | 3.7     | 1.0     | 3.7   | 0.9     | 3.7   | ns |
|                  | propagation delay  | DIR to B                      | 2.3     | 13.1    | 2.4     | 12.1   | 1.9     | 7.4     | 2.3     | 7.0   | 1.8     | 4.5   | ns |
| t <sub>PZH</sub> | propagation delay D  t <sub>PZL</sub> OFF-state to LOW D | DIR to A [1]                  | -       | 23.6    | -       | 18.9   | -       | 12.2    | -       | 11.4  | -       | 8.4   | ns |
|                  |  | DIR to B [1]                  | -       | 20.3    | -       | 18.8   | -       | 11.2    | -       | 9.1   | -       | 7.6   | ns |
| t <sub>PZL</sub> |  | DIR to A [1]                  | -       | 28.1    | -       | 23.1   | -       | 14.3    | -       | 12.0  | -       | 9.2   | ns |
|                  |  | DIR to B [1]                  | -       | 20.7    | -       | 17.6   | -       | 11.6    | -       | 9.9   | -       | 8.9   | ns |

<sup>[1]</sup> t<sub>PZH</sub> and t<sub>PZL</sub> are calculated values using the formula shown in <u>Section 14.4 "Enable times"</u>

Table 13. Dynamic characteristics for temperature range -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7

| Symbol               | Parameter         | Conditions   |       |         |         |        | Vcc     | C(B)    |         |         |       |         | Unit |
|----------------------|-------------------|--------------|-------|---------|---------|--------|---------|---------|---------|---------|-------|---------|------|
|                      |                   |              | 1.5 V | ± 0.1 V | 1.8 V ± | 0.15 V | 2.5 V : | ± 0.2 V | 3.3 V : | ± 0.3 V | 5.0 V | ± 0.5 V |      |
|                      |                   |              | Min   | Max     | Min     | Max    | Min     | Max     | Min     | Max     | Min   | Max     |      |
| V <sub>CC(A)</sub> = | 1.4 V to 1.6 V    |              |       |         |         |        |         |         |         |         |       |         |      |
| t <sub>PLH</sub>     | LOW to HIGH       | A to B       | 2.5   | 23.5    | 2.1     | 19.4   | 1.8     | 14.9    | 1.5     | 13.0    | 1.4   | 11.6    | ns   |
|                      | propagation delay | B to A       | 2.5   | 23.5    | 2.3     | 21.1   | 2.0     | 16.4    | 2.0     | 13.7    | 1.9   | 13.2    | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.3   | 21.3    | 1.9     | 16.9   | 1.6     | 13.0    | 1.5     | 12.0    | 1.5   | 11.9    | ns   |
|                      | propagation delay | B to A       | 2.3   | 21.3    | 2.1     | 19.1   | 2.0     | 14.6    | 1.9     | 12.5    | 2.0   | 12.1    | ns   |
| t <sub>PHZ</sub>     | HIGH to OFF-state | DIR to A     | 2.7   | 20.6    | 2.7     | 20.6   | 2.7     | 20.6    | 2.7     | 20.6    | 2.7   | 20.6    | ns   |
|                      | propagation delay | DIR to B     | 3.1   | 27.3    | 3.1     | 26.0   | 2.7     | 12.1    | 2.9     | 12.5    | 2.5   | 11.4    | ns   |
| $t_{PLZ}$            | LOW to OFF-state  | DIR to A     | 2.1   | 12.6    | 2.1     | 12.6   | 2.1     | 12.6    | 2.1     | 12.6    | 2.1   | 12.6    | ns   |
|                      | propagation delay | DIR to B     | 2.5   | 20.2    | 2.7     | 19.0   | 2.2     | 10.4    | 2.7     | 11.2    | 2.2   | 10.4    | ns   |
| t <sub>PZH</sub>     | OFF-state to HIGH | DIR to A 🗓   | -     | 43.7    | -       | 40.1   | -       | 26.8    | -       | 24.9    | -     | 23.6    | ns   |
|                      | propagation delay | DIR to B [1] | -     | 36.1    | -       | 32.0   | -       | 27.5    | -       | 25.6    | -     | 24.2    | ns   |
| t <sub>PZL</sub>     | OFF-state to LOW  | DIR to A 🗓   | -     | 48.6    | -       | 45.1   | -       | 26.7    | -       | 25.0    | -     | 23.5    | ns   |
|                      | propagation delay | DIR to B [1] | -     | 41.9    | -       | 37.5   | -       | 33.6    | -       | 32.6    | -     | 32.5    | ns   |
| V <sub>CC(A)</sub> = | 1.65 V to 1.95 V  |              |       |         |         |        |         |         |         |         |       |         |      |
| t <sub>PLH</sub>     | LOW to HIGH       | A to B       | 2.3   | 21.1    | 1.9     | 19.5   | 1.9     | 10.3    | 1.5     | 8.0     | 1.2   | 7.5     | ns   |
|                      | propagation delay | B to A       | 2.1   | 19.4    | 1.9     | 19.5   | 2.0     | 17.6    | 1.8     | 17.1    | 1.7   | 16.7    | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.1   | 19.1    | 1.8     | 15.8   | 1.4     | 9.4     | 1.6     | 7.9     | 1.5   | 7.7     | ns   |
|                      | propagation delay | B to A       | 1.9   | 16.9    | 1.8     | 15.8   | 1.8     | 14.2    | 1.8     | 13.9    | 1.6   | 13.5    | ns   |
| t <sub>PHZ</sub>     | HIGH to OFF-state | DIR to A     | 2.6   | 18.9    | 2.6     | 18.9   | 2.6     | 18.9    | 2.6     | 18.9    | 2.6   | 18.9    | ns   |
|                      | propagation delay | DIR to B     | 2.8   | 26.6    | 2.8     | 24.1   | 2.4     | 12.7    | 2.7     | 11.4    | 2.2   | 9.1     | ns   |
| t <sub>PLZ</sub>     | LOW to OFF-state  | DIR to A     | 2.1   | 11.6    | 2.1     | 11.6   | 2.1     | 11.6    | 2.1     | 11.6    | 2.1   | 11.6    | ns   |
|                      | propagation delay | DIR to B     | 2.2   | 19.4    | 2.3     | 17.6   | 1.9     | 10.2    | 2.4     | 9.3     | 2.1   | 7.4     | ns   |
| t <sub>PZH</sub>     | OFF-state to HIGH | DIR to A [1] | -     | 38.8    | -       | 37.1   | -       | 27.8    | -       | 26.4    | -     | 24.1    | ns   |
|                      | propagation delay | DIR to B [1] | -     | 32.7    | -       | 31.1   | -       | 21.9    | -       | 19.6    | -     | 19.1    | ns   |
|                      |                   |              |       |         |         |        |         |         |         |         |       |         |      |

Table 13. Dynamic characteristics for temperature range –40 °C to +125 °C ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7

| Symbol               | Parameter         | Conditions   |       | V <sub>CC(B)</sub> |         |          |       |         |         |         |         |         | Unit |
|----------------------|-------------------|--------------|-------|--------------------|---------|----------|-------|---------|---------|---------|---------|---------|------|
|                      |                   |              | 1.5 V | ± 0.1 V            | 1.8 V : | Ŀ 0.15 V | 2.5 V | ± 0.2 V | 3.3 V : | ± 0.3 V | 5.0 V = | ± 0.5 V |      |
|                      |                   |              | Min   | Max                | Min     | Max      | Min   | Max     | Min     | Max     | Min     | Max     |      |
| t <sub>PZL</sub>     | OFF-state to LOW  | DIR to A [1] | -     | 43.5               | -       | 39.9     | -     | 26.9    | -       | 25.3    | -       | 22.6    | ns   |
|                      | propagation delay | DIR to B     | -     | 38.0               | -       | 34.7     | -     | 28.3    | -       | 26.8    | -       | 26.6    | ns   |
| V <sub>CC(A)</sub> = | 2.3 V to 2.7 V    |              |       |                    |         |          |       |         |         |         |         |         |      |
| t <sub>PLH</sub>     | LOW to HIGH       | A to B       | 2.0   | 19.7               | 2.0     | 17.6     | 1.3   | 9.4     | 1.1     | 6.9     | 0.9     | 5.3     | ns   |
|                      | propagation delay | B to A       | 1.8   | 14.9               | 1.9     | 10.3     | 1.3   | 9.4     | 1.2     | 8.8     | 0.9     | 8.3     | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.0   | 17.4               | 1.8     | 14.2     | 1.2   | 8.3     | 1.1     | 6.0     | 8.0     | 5.1     | ns   |
|                      | propagation delay | B to A       | 1.6   | 13.0               | 1.7     | 9.4      | 1.2   | 8.3     | 1.1     | 7.7     | 8.0     | 6.9     | ns   |
| $t_{\text{PHZ}}$     | HIGH to OFF-state | DIR to A     | 1.8   | 9.0                | 1.8     | 9.0      | 1.8   | 9.0     | 1.8     | 9.0     | 1.8     | 9.0     | ns   |
|                      | propagation delay | DIR to B     | 2.7   | 24.8               | 2.7     | 23.6     | 2.2   | 12.1    | 2.5     | 10.3    | 2.0     | 7.6     | ns   |
| $t_{\text{PLZ}}$     | LOW to OFF-state  | DIR to A     | 1.5   | 6.4                | 1.5     | 6.4      | 1.5   | 6.4     | 1.5     | 6.4     | 1.5     | 6.4     | ns   |
|                      | propagation delay | DIR to B     | 2.0   | 16.1               | 2.2     | 14.6     | 1.8   | 9.9     | 2.2     | 9.3     | 1.6     | 5.9     | ns   |
| $t_{PZH}$            | OFF-state to HIGH | DIR to A [1] | -     | 31.0               | -       | 24.9     | -     | 19.3    | -       | 18.1    | -       | 14.2    | ns   |
|                      | propagation delay | DIR to B     | -     | 26.1               | -       | 24.0     | -     | 15.8    | -       | 13.3    | -       | 11.7    | ns   |
| $t_{PZL}$            | OFF-state to LOW  | DIR to A     | -     | 37.8               | -       | 33.0     | -     | 20.4    | -       | 18.0    | -       | 14.5    | ns   |
|                      | propagation delay | DIR to B     | -     | 26.4               | -       | 23.2     | -     | 17.3    | -       | 15.0    | -       | 14.1    | ns   |
| $V_{CC(A)} =$        | 3.0 V to 3.6 V    |              |       |                    |         |          |       |         |         |         |         |         |      |
| $t_{PLH}$            | LOW to HIGH       | A to B       | 2.0   | 18.9               | 1.8     | 17.1     | 1.2   | 8.8     | 0.7     | 6.2     | 0.6     | 4.9     | ns   |
|                      | propagation delay | B to A       | 1.5   | 13.0               | 1.5     | 8.0      | 1.1   | 6.9     | 0.6     | 6.2     | 0.5     | 6.0     | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 1.9   | 17.2               | 1.8     | 13.9     | 1.1   | 7.7     | 0.7     | 5.5     | 0.6     | 4.4     | ns   |
|                      | propagation delay | B to A       | 1.5   | 12.0               | 1.6     | 7.9      | 1.1   | 6.0     | 0.7     | 5.5     | 0.6     | 5.0     | ns   |
| $t_{\text{PHZ}}$     | HIGH to OFF-state | DIR to A     | 2.0   | 8.1                | 2.0     | 8.1      | 2.0   | 8.1     | 2.0     | 8.1     | 2.4     | 8.1     | ns   |
|                      | propagation delay | DIR to B     | 2.6   | 19.8               | 2.6     | 18.2     | 2.0   | 11.2    | 2.4     | 9.5     | 1.9     | 7.0     | ns   |
| $t_{PLZ}$            | LOW to OFF-state  | DIR to A     | 1.8   | 6.2                | 1.8     | 6.2      | 1.8   | 6.2     | 1.8     | 6.2     | 1.8     | 6.2     | ns   |
|                      | propagation delay | DIR to B     | 2.0   | 15.0               | 2.1     | 13.8     | 1.7   | 8.6     | 2.0     | 7.9     | 1.5     | 5.4     | ns   |
| $t_{PZH}$            | OFF-state to HIGH | DIR to A [1] | -     | 28.0               | -       | 21.8     | -     | 15.5    | -       | 14.1    | -       | 11.4    | ns   |
|                      | propagation delay | DIR to B     | -     | 25.1               | -       | 23.3     | -     | 15.0    | -       | 12.4    | -       | 11.1    | ns   |
| $t_{PZL}$            | OFF-state to LOW  | DIR to A [1] | -     | 31.8               | -       | 26.1     | -     | 17.2    | -       | 15.0    | -       | 12.0    | ns   |
|                      | propagation delay | DIR to B     | -     | 25.3               | -       | 22.0     | -     | 15.8    | -       | 13.6    | -       | 12.5    | ns   |
| $V_{CC(A)} =$        | 4.5 V to 5.5 V    |              |       |                    |         |          |       |         |         |         |         |         |      |
| $t_{PLH}$            | LOW to HIGH       | A to B       | 1.9   | 18.3               | 1.7     | 16.7     | 0.9   | 8.3     | 0.6     | 6.0     | 0.4     | 4.3     | ns   |
|                      | propagation delay | B to A       | 1.4   | 11.6               | 1.2     | 7.5      | 0.9   | 5.3     | 0.6     | 4.9     | 0.4     | 4.3     | ns   |
| t <sub>PHL</sub>     | HIGH to LOW       | A to B       | 2.0   | 16.9               | 1.6     | 13.5     | 0.9   | 6.9     | 0.6     | 5.0     | 0.4     | 3.9     | ns   |
|                      | propagation delay | B to A       | 1.5   | 11.9               | 1.5     | 7.7      | 8.0   | 5.1     | 0.6     | 4.4     | 0.4     | 3.9     | ns   |
| $t_{\text{PHZ}}$     | HIGH to OFF-state | DIR to A     | 1.5   | 6.0                | 1.5     | 6.0      | 1.5   | 6.0     | 1.5     | 6.0     | 1.5     | 6.0     | ns   |
|                      | propagation delay | DIR to B     | 2.6   | 19.1               | 2.6     | 17.8     | 2.0   | 10.7    | 2.4     | 8.8     | 2.2     | 6.3     | ns   |
| $t_{PLZ}$            | LOW to OFF-state  | DIR to A     | 1.2   | 4.1                | 1.2     | 4.1      | 1.1   | 4.1     | 0.9     | 4.1     | 8.0     | 4.1     | ns   |
|                      | propagation delay | DIR to B     | 2.0   | 14.5               | 2.1     | 13.4     | 1.7   | 8.2     | 2.0     | 7.7     | 1.6     | 5.0     | ns   |
|                      |                   |              |       |                    |         |          |       |         |         |         |         |         |      |

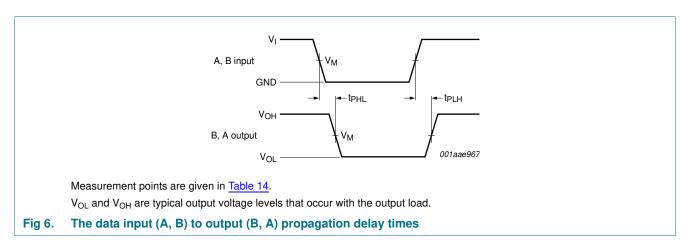
Table 13. Dynamic characteristics for temperature range –40 °C to +125 °C ...continued

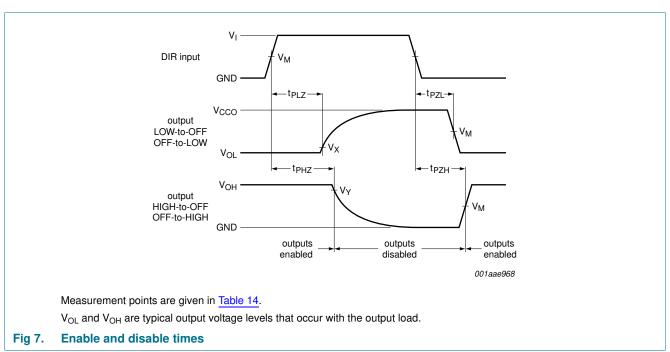
Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8; for wave forms see Figure 6 and Figure 7

| J                |                   | 77         |          |       |       |         |        |                 |       |                     |      |                 |      |      |
|------------------|-------------------|------------|----------|-------|-------|---------|--------|-----------------|-------|---------------------|------|-----------------|------|------|
| Symbol           | Parameter         | Conditions |          |       |       |         |        | V <sub>CC</sub> | (B)   |                     |      |                 |      | Unit |
|                  |                   |            | 1.5      | 5 V ± | 0.1 V | 1.8 V ± | 0.15 V | 2.5 V ±         | 0.2 V | $/ 3.3 V \pm 0.3 V$ |      | V 5.0 V ± 0.5 V |      |      |
|                  |                   |            | М        | lin   | Max   | Min     | Max    | Min             | Max   | Min                 | Max  | Min             | Max  |      |
| $t_{PZH}$        | OFF-state to HIGH | DIR to A   | <u> </u> | -     | 26.1  | -       | 20.9   | -               | 13.5  | -                   | 12.6 | -               | 9.3  | ns   |
|                  | propagation delay | DIR to B   | 1] .     | -     | 22.4  | -       | 20.8   | -               | 12.4  | -                   | 10.1 | -               | 8.4  | ns   |
| t <sub>PZL</sub> | OFF-state to LOW  | DIR to A   | 1] .     | -     | 31.0  | -       | 25.5   | -               | 15.8  | -                   | 13.2 | -               | 10.2 | ns   |
|                  | propagation delay | DIR to B   | <u>.</u> | -     | 22.9  | -       | 19.5   | -               | 12.9  | -                   | 11.0 | -               | 9.9  | ns   |

<sup>[1]</sup> t<sub>PZH</sub> and t<sub>PZL</sub> are calculated values using the formula shown in Section 14.4 "Enable times"

#### 12. Waveforms



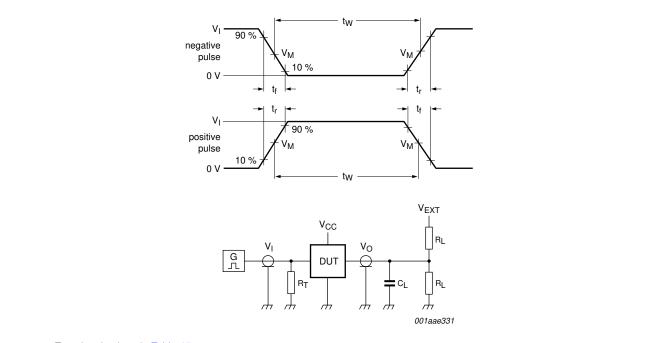


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Table 14. Measurement points

| Supply voltage                          | Input <sup>[1]</sup> | Output[2]           |                          |                          |
|---|----------------------|---------------------|--------------------------|--------------------------|
| V <sub>CC(A)</sub> , V <sub>CC(B)</sub> | V <sub>M</sub>       | V <sub>M</sub>      | V <sub>X</sub>           | V <sub>Y</sub>           |
| 1.2 V to 1.6 V                          | 0.5V <sub>CCI</sub>  | 0.5V <sub>CCO</sub> | V <sub>OL</sub> + 0.1 V  | $V_{OH}-0.1\ V$          |
| 1.65 V to 2.7 V                         | 0.5V <sub>CCI</sub>  | 0.5V <sub>CCO</sub> | V <sub>OL</sub> + 0.15 V | V <sub>OH</sub> – 0.15 V |
| 3.0 V to 5.5 V                          | 0.5V <sub>CCI</sub>  | 0.5V <sub>CCO</sub> | $V_{OL} + 0.3 V$         | $V_{OH} - 0.3 V$         |

- [1]  $V_{CCI}$  is the supply voltage associated with the data input port.
- [2] V<sub>CCO</sub> is the supply voltage associated with the output port.



Test data is given in <u>Table 15</u>.

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

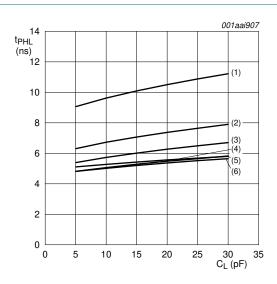
Table 15. Test data

| Supply voltage         | Input              |                 | Load  | Load           |                                     | V <sub>EXT</sub>                    |   |  |  |
|------------------------|--------------------|-----------------|-------|----------------|-------------------------------------|-------------------------------------|---|--|--|
| $V_{CC(A)}, V_{CC(B)}$ | V <sub>I</sub> [1] | Δt/ΔV[2]        | CL    | R <sub>L</sub> | t <sub>PLH</sub> , t <sub>PHL</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> [3] |  |  |
| 1.2 V to 5.5 V         | $V_{CCI}$          | $\leq$ 1.0 ns/V | 15 pF | 2 kΩ           | open                                | GND                                 | 2V <sub>CCO</sub>                       |  |  |

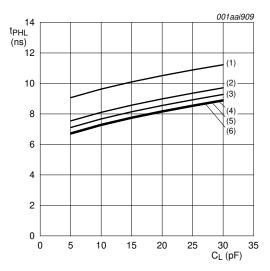
- [1] V<sub>CCI</sub> is the supply voltage associated with the data input port.
- [2] dV/dt ≥ 1.0 V/ns
- [3]  $V_{\text{CCO}}$  is the supply voltage associated with the output port.

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# 13. Typical propagation delay characteristics

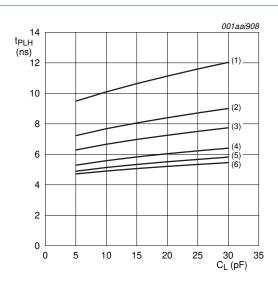


a. HIGH to LOW propagation delay (A to B)

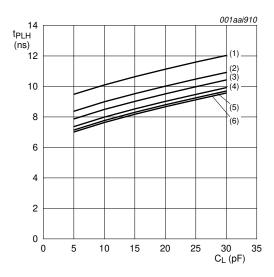


- c. HIGH to LOW propagation delay (B to A)
- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

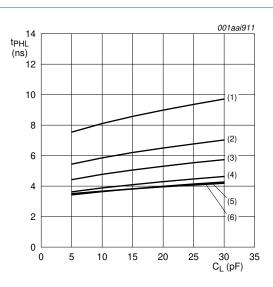
Fig 9. Typical propagation delay vs load capacitance; T<sub>amb</sub> = 25 °C; V<sub>CC(A)</sub> = 1.2 V

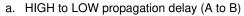


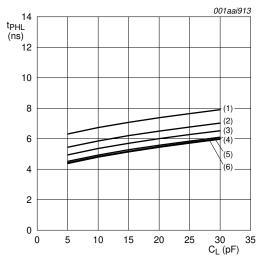
b. LOW to HIGH propagation delay (A to B)



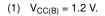
d. LOW to HIGH propagation delay (B to A)





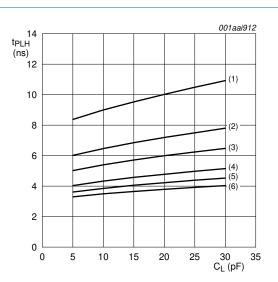


c. HIGH to LOW propagation delay (B to A)

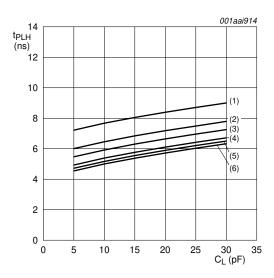


- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

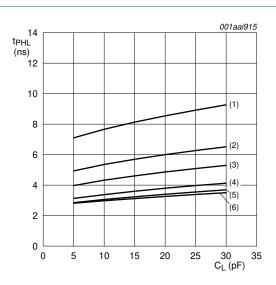
Fig 10. Typical propagation delay vs load capacitance; T<sub>amb</sub> = 25 °C; V<sub>CC(A)</sub> = 1.5 V

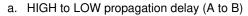


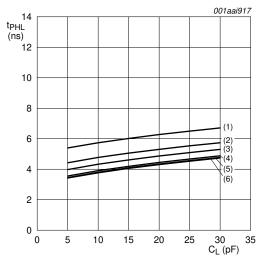
b. LOW to HIGH propagation delay (A to B)



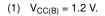
d. LOW to HIGH propagation delay (B to A)





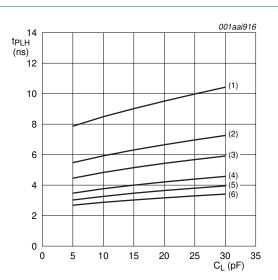


c. HIGH to LOW propagation delay (B to A)

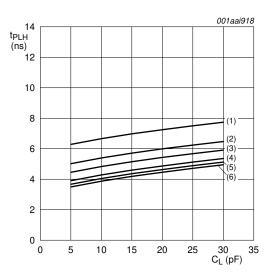


- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

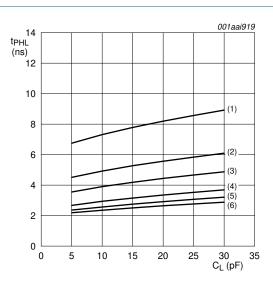
Fig 11. Typical propagation delay vs load capacitance; T<sub>amb</sub> = 25 °C; V<sub>CC(A)</sub> = 1.8 V

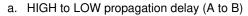


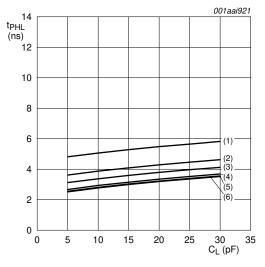
b. LOW to HIGH propagation delay (A to B)



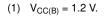
d. LOW to HIGH propagation delay (B to A)





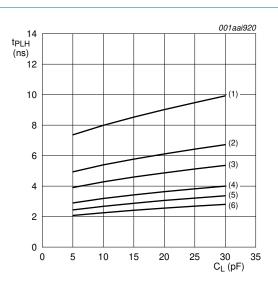


c. HIGH to LOW propagation delay (B to A)

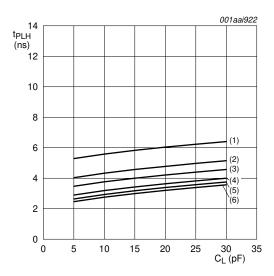


- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

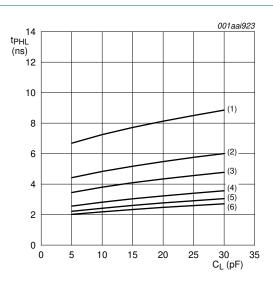
Fig 12. Typical propagation delay vs load capacitance; T<sub>amb</sub> = 25 °C; V<sub>CC(A)</sub> = 2.5 V

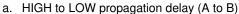


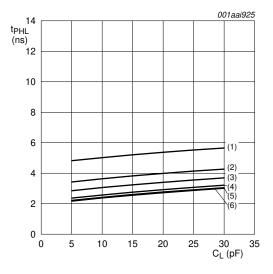
b. LOW to HIGH propagation delay (A to B)



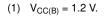
d. LOW to HIGH propagation delay (B to A)





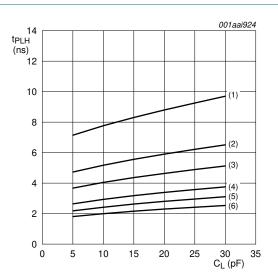


c. HIGH to LOW propagation delay (B to A)

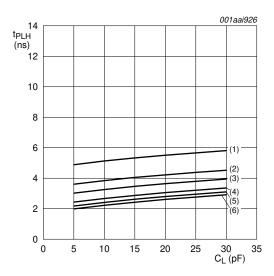


- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

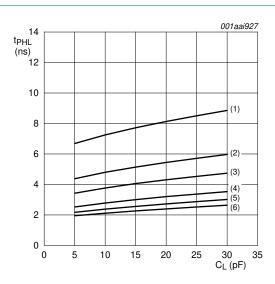
Fig 13. Typical propagation delay vs load capacitance; T<sub>amb</sub> = 25 °C; V<sub>CC(A)</sub> = 3.3 V

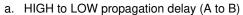


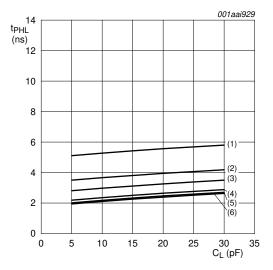
b. LOW to HIGH propagation delay (A to B)



d. LOW to HIGH propagation delay (B to A)





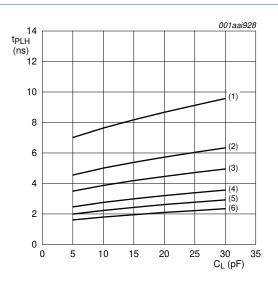


c. HIGH to LOW propagation delay (B to A)

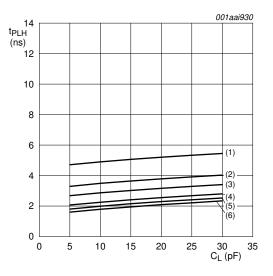


- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$
- (4)  $V_{CC(B)} = 2.5 \text{ V}.$
- (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

Fig 14. Typical propagation delay vs load capacitance;  $T_{amb} = 25 \, ^{\circ}C$ ;  $V_{CC(A)} = 5 \, V$ 



b. LOW to HIGH propagation delay (A to B)



d. LOW to HIGH propagation delay (B to A)

# 14. Application information

#### 14.1 Unidirectional logic level-shifting application

The circuit given in <u>Figure 15</u> is an example of the 74LVC1T45; 74LVCH1T45 being used in a unidirectional logic level-shifting application.

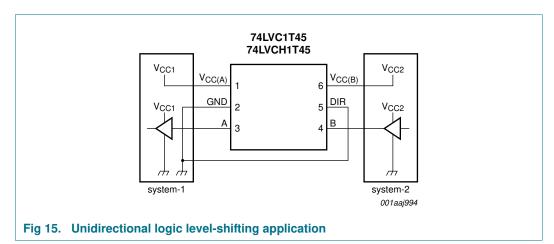
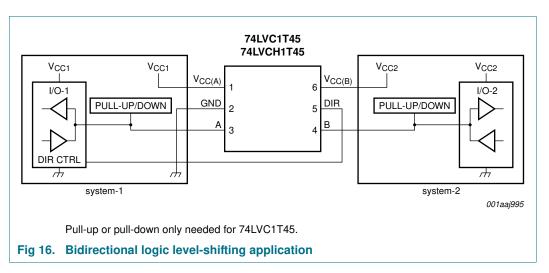


Table 16. Description unidirectional logic level-shifting application

| Pin | Name        | Function  | Description   |
|-----|-------------|-----------|---|
| 1   | $V_{CC(A)}$ | $V_{CC1}$ | supply voltage of system-1 (1.2 V to 5.5 V)               |
| 2   | GND         | GND       | device GND  |
| 3   | Α           | OUT       | output level depends on V <sub>CC1</sub> voltage          |
| 4   | В           | IN        | input threshold value depends on V <sub>CC2</sub> voltage |
| 5   | DIR         | DIR       | the GND (LOW level) determines B port to A port direction |
| 6   | $V_{CC(B)}$ | $V_{CC2}$ | supply voltage of system-2 (1.2 V to 5.5 V)               |

#### 14.2 Bidirectional logic level-shifting application

<u>Figure 16</u> shows the 74LVC1T45; 74LVCH1T45 being used in a bidirectional logic level-shifting application. Since the device does not have an output enable pin, the system designer should take precautions to avoid bus contention between system-1 and system-2 when changing directions.



<u>Table 17</u> provides a sequence that illustrates data transmission from system-1 to system-2 and then from system-2 to system-1.

Table 17. Description bidirectional logic level-shifting application[1]

| State | DIR CTRL | I/O-1  | I/O-2  | Description   |
|-------|----------|--------|--------|---|
| 1     | Н        | output | input  | system-1 data to system-2   |
| 2     | Н        | Z      | Z      | system-2 is getting ready to send data to system-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on bus hold. |
| 3     | L        | Z      | Z      | DIR bit is set LOW. I/O-1 and I/O-2 are still disabled. The bus-line state depends on bus hold.                           |
| 4     | L        | input  | output | system-2 data to system-1   |

<sup>[1]</sup> H = HIGH voltage level;

L = LOW voltage level;

Z = high-impedance OFF-state.

#### 14.3 Power-up considerations

The device is designed such that no special power-up sequence is required other than GND being applied first.

Table 18. Typical total supply current  $(I_{CC(A)} + I_{CC(B)})$ 

|                    |                    |       | ` '   | · /   |       |      |  |
|--------------------|--------------------|-------|-------|-------|-------|------|--|
| V <sub>CC(A)</sub> | V <sub>CC(B)</sub> |       |       |       |       | Unit |  |
|                    | 0 V                | 1.8 V | 2.5 V | 3.3 V | 5.0 V |      |  |
| 0 V                | 0                  | < 1   | < 1   | < 1   | < 1   | μΑ   |  |
| 1.8 V              | < 1                | < 2   | < 2   | < 2   | 2     | μΑ   |  |
| 2.5 V              | < 1                | < 2   | < 2   | < 2   | < 2   | μΑ   |  |
| 3.3 V              | < 1                | < 2   | < 2   | < 2   | < 2   | μΑ   |  |
| 5.0 V              | < 1                | 2     | < 2   | < 2   | < 2   | μΑ   |  |

#### 14.4 Enable times

Calculate the enable times for the 74LVC1T45; 74LVCH1T45 using the following formulas:

- $t_{PZH}$  (DIR to A) =  $t_{PLZ}$  (DIR to B) +  $t_{PLH}$  (B to A)
- $t_{PZL}$  (DIR to A) =  $t_{PHZ}$  (DIR to B) +  $t_{PHL}$  (B to A)
- $t_{PZH}$  (DIR to B) =  $t_{PLZ}$  (DIR to A) +  $t_{PLH}$  (A to B)
- $t_{PZL}$  (DIR to B) =  $t_{PHZ}$  (DIR to A) +  $t_{PHL}$  (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the 74LVC1T45; 74LVCH1T45 initially is transmitting from A to B, then the DIR bit is switched, the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

# 15. Package outline

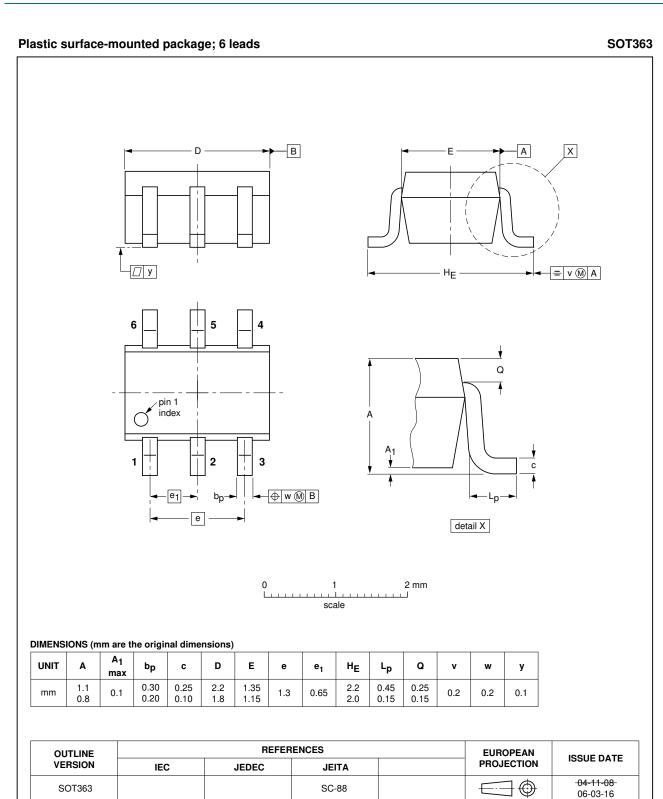


Fig 17. Package outline SOT363 (SC-88)

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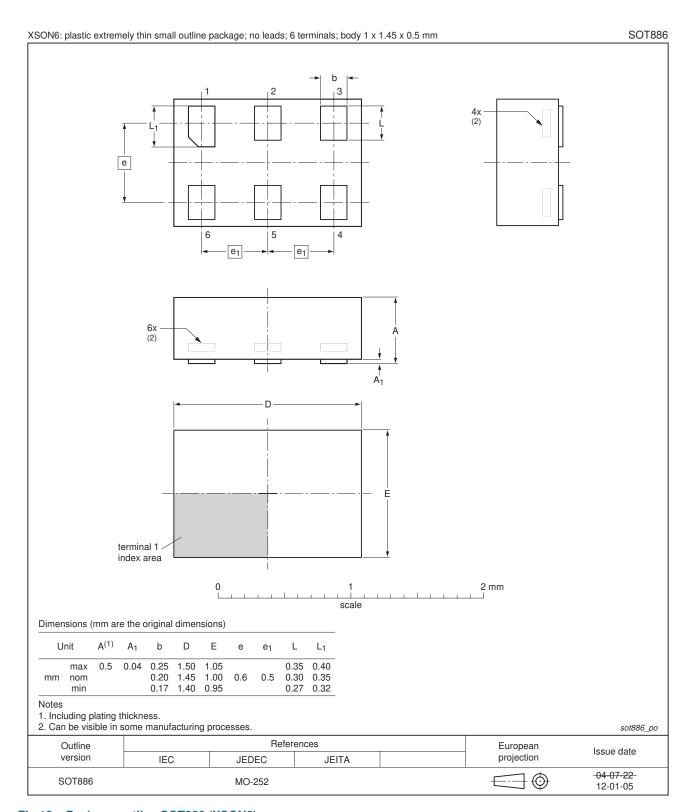


Fig 18. Package outline SOT886 (XSON6)

74LVC\_LVCH1T45

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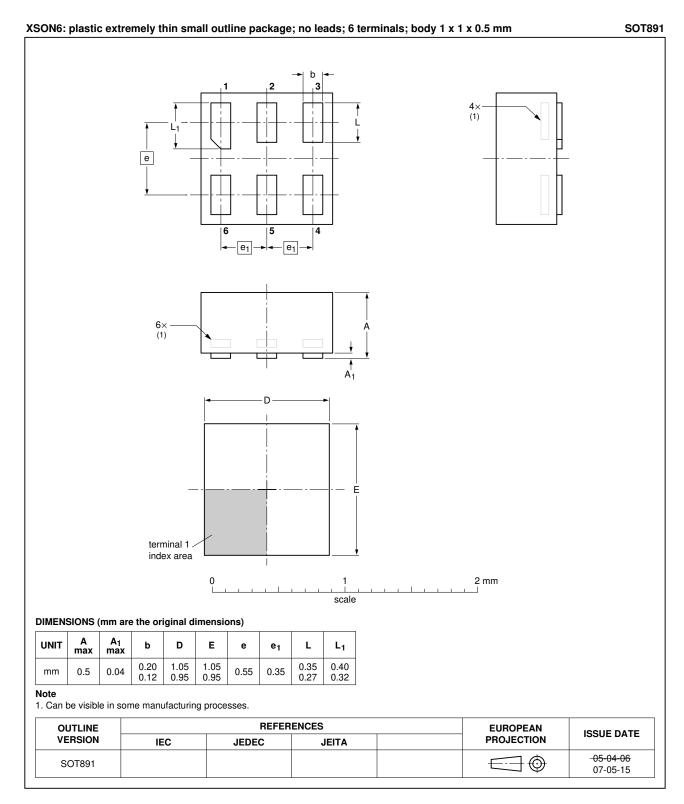


Fig 19. Package outline SOT891 (XSON6)

74LVC\_LVCH1T45

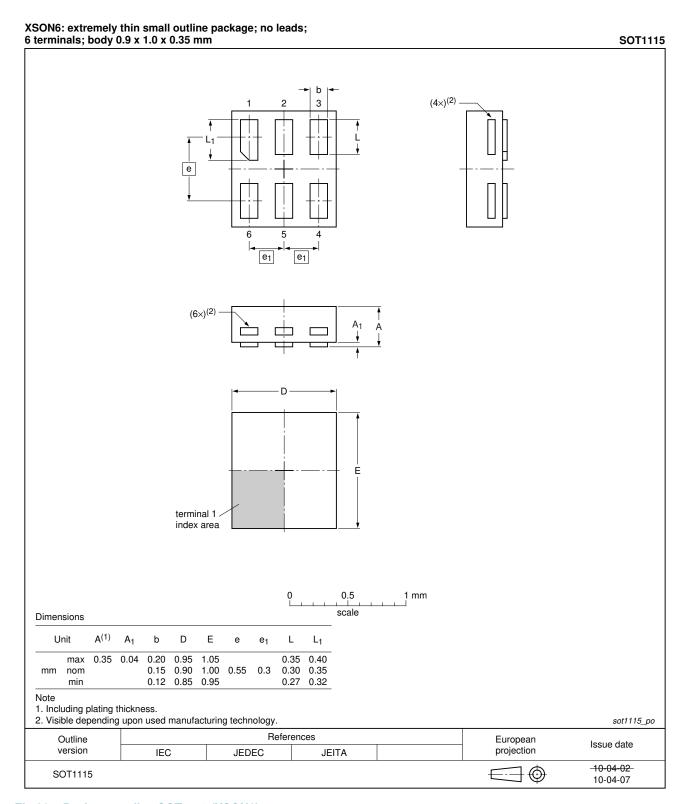


Fig 20. Package outline SOT1115 (XSON6)

74LVC\_LVCH1T45

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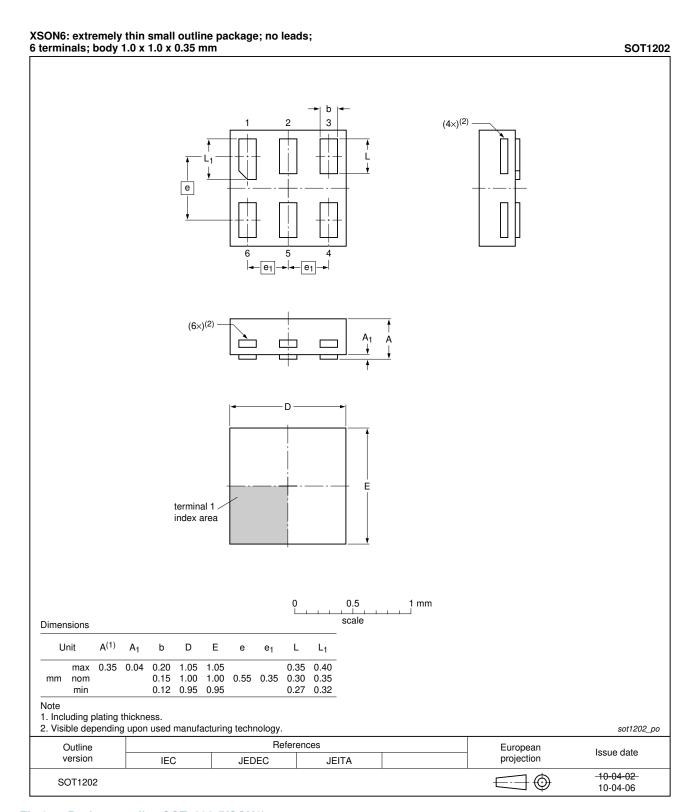


Fig 21. Package outline SOT1202 (XSON6)

74LVC\_LVCH1T45

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## 16. Abbreviations

#### Table 19. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| НВМ     | Human Body Model        |

# 17. Revision history

#### Table 20. Revision history

| Document ID        | Release date                    | Data sheet status                          | Change notice    | Supersedes         |
|--------------------|---------------------------------|--|------------------|--------------------|
| 74LVC_LVCH1T45 v.6 | 20120806                        | Product data sheet                         | -                | 74LVC_LVCH1T45 v.5 |
| Modifications:     | <ul> <li>Package out</li> </ul> | line drawing of SOT886 ( <mark>Figu</mark> | re 18) modified. |                    |
| 74LVC_LVCH1T45 v.5 | 20111219                        | Product data sheet                         | -                | 74LVC_LVCH1T45 v.4 |
| Modifications:     | <ul> <li>Legal pages</li> </ul> | updated.                                   |                  |                    |
| 74LVC_LVCH1T45 v.4 | 20110927                        | Product data sheet                         | -                | 74LVC_LVCH1T45 v.3 |
| 74LVC_LVCH1T45 v.3 | 20100819                        | Product data sheet                         | -                | 74LVC_LVCH1T45 v.2 |
| 74LVC_LVCH1T45 v.2 | 20100119                        | Product data sheet                         | -                | 74LVC_LVCH1T45 v.1 |
| 74LVC_LVCH1T45 v.1 | 20090511                        | Product data sheet                         | -                | -                  |
|                    |                                 |  |                  |                    |

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#### 18.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# 74LVC1T45; 74LVCH1T45

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